

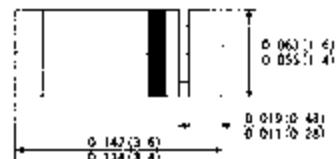
# ZMM1 THRU ZMM200

## 0.5W SILICON PLANAR ZENER DIODES

### FEATURES

- . In MiniMELF case especially for automated insertion
- The zener voltage are graded according to the international E24 standard. Smaller voltage tolerances and higher zener voltage on request

### Mini-MELF



Dimensions in inches and (millimeters)

### MECHANICAL DATA

- . **Case:** Mini-MELF(SOD-80) glass case
- . **weight:** Approx. 0.05 gram

### ABSOLUTE MAXIMUM RATINGS(LIMITING VALUES)(TA=25°C)

	Symbols	Value	Units
Zener current see table "Characteristics"			
Power dissipation at TA=25°C	P <sub>tot</sub>	500 1)	mW
Junction temperature	T <sub>J</sub>	175	°C
Storage temperature range	T <sub>STG</sub>	-55 to +175	°C

1)Valid provided that a distance of 8mm from case are kept at ambient temperature

### ELECTRICAL CHARACTERISTICS(TA=25°C)

	Symbols	Min	Typ	Max	Units
Thermal resistance junction to ambient	R <sub>θA</sub>			300 1)	K/W
1) Valid provided that a distance at 8mm from case are kept at ambient temperature					

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### ZMM1 THRU ZMM200 SILICON PLANAR ZENER DIODES

Type	Zener Voltage range 1)			Dynamic resistance 1)			Maximum reverse Leakage Current			of zener voltage										
	V <sub>znom</sub> 3)	I <sub>ZT</sub>		r <sub>Zjt</sub> and r <sub>Zjk</sub> at I <sub>ZK</sub>			I <sub>R</sub> and I <sub>R</sub> at V <sub>R</sub> 2)		TK <sub>VZ</sub>											
		v	mA	V	Ω	Ω	mA	μA	μA	V	%/K									
ZMM1 <sup>3)</sup>	0.75	5		0.7..0.8	<8	<50	1	--	--	--	-0.26..-0.23									
ZMM2.0	2.0			1.9..2.1	<85	<600		<100	<200	1	-0.09..-0.06									
ZMM2.4	2.4			2.28..2.56				<50	<100		-0.09..-0.06									
ZMM2.7	2.7			2.5..2.9				<10	<50		-0.09..-0.06									
ZMM3.0	3.0			2.8..3.2				<4	<40		-0.08..-0.05									
ZMM3.3	3.3			3.1..3.5				<2			-0.08..-0.05									
ZMM3.6	3.6			3.4..3.8				<2			-0.08..-0.05									
ZMM3.9	3.9			3.7..4.1				<2			-0.08..-0.05									
ZMM4.3	4.3			4.0..4.6	<75	<220		<1	<20		-0.06..-0.03									
ZMM4.7	4.7			4.4..5.0	<60			<0.5	<10		-0.05..±0.05									
ZMM5.1	5.1			4.8..5.4	<35			<0.1	<10		-0.02..±0.02									
ZMM5.6	5.6			5.2..6.0	<25						-0.05..±0.05									
ZMM6.2	6.2			5.8..6.6	<10	<200					2 0.03..0.06									
ZMM6.8	6.8			6.4..7.2	<8	<150					3 0.03..0.07									
ZMM7.5	7.5			7.0..7.9	<7	<220					5 0.03..0.08									
ZMM8.2	8.2			7.7..8.7	<7						6.2 0.03..0.09									
ZMM9.1	9.1			8.5..9.6	<10						6.8 0.03..0.1									
ZMM10	10			9.4..10.6	<15	<70					7.5 0.03..0.11									
ZMM11	11			10.4..11.6	<20	<70					8.2 0.03..0.11									
ZMM12	12			11.4..12.7	<20	<90					9.1 0.03..0.11									
ZMM13	13			12.4..14.1	<26	<110					10 0.03..0.11									
ZMM15	15			13.8..15.6	<30	<110					11 0.03..0.11									
ZMM16	16			15.3..17.1	<40	<170					12 0.03..0.11									
ZMM18	18			16.8..19.1	<50	<170					13 0.03..0.11									
ZMM20	20			18.8..21.2	<55	<220		<5			15 0.03..0.11									
ZMM22	22			20.8..23.3	<55						16									
ZMM24	24			22.8..25.6	<220						18									
ZMM27	27			25.1..28.9							20									
ZMM30	30			28..32							22									
ZMM33	33			31..35							24									
ZMM36	36			34..38							27									
ZMM39	39	2.5		37..41	<90	<500	0.1	<10	<5	0.04..0.12	30									
ZMM43	43			40..46	33															
ZMM47	47			44..50	<110	<600					36									
ZMM51	51			48..54	<125	<1000					39									
ZMM56	56			52..60	<135						43									
ZMM62	62			58..66	<150						47									
ZMM68	68			64..72	<200						51									
ZMM75	75			70..79	<250						56									
ZMM82	82			77..87	<300	<1500					62									
ZMM91	91	1		85..96	<450	<2000					68									
ZMM100	100			94..106	<450	<10000					75									
ZMM110	110			104..116	<600						82									
ZMM120	120			114..127	<800						91									
ZMM130	130			124..141	<950						100									
ZMM150	150			138..156	<1250						110									
ZMM160	160			153..171	<1400						120									
ZMM180	180			168..191	<1700						130									
ZMM200	200			188..212	<2000						150									

1) Tested with pulse tp=20ms

2) Valid provided that electrodes are kept at ambient temperature

3) The ZMM1 is a silicon diode with operation in forward direction. Hence, the index of all parameters should be "F" instead of "Z".

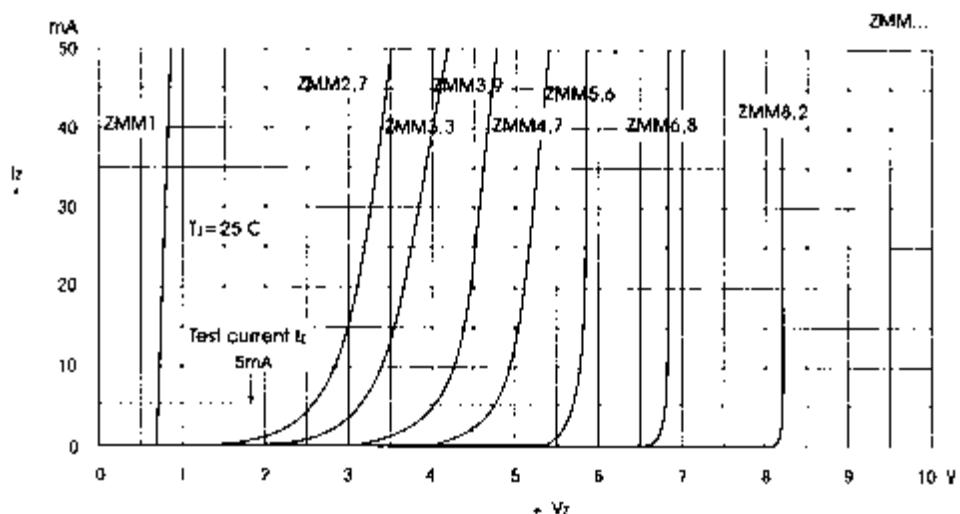
Connect the cathode to the negative pole.

# ZMM1 THRU ZMM200

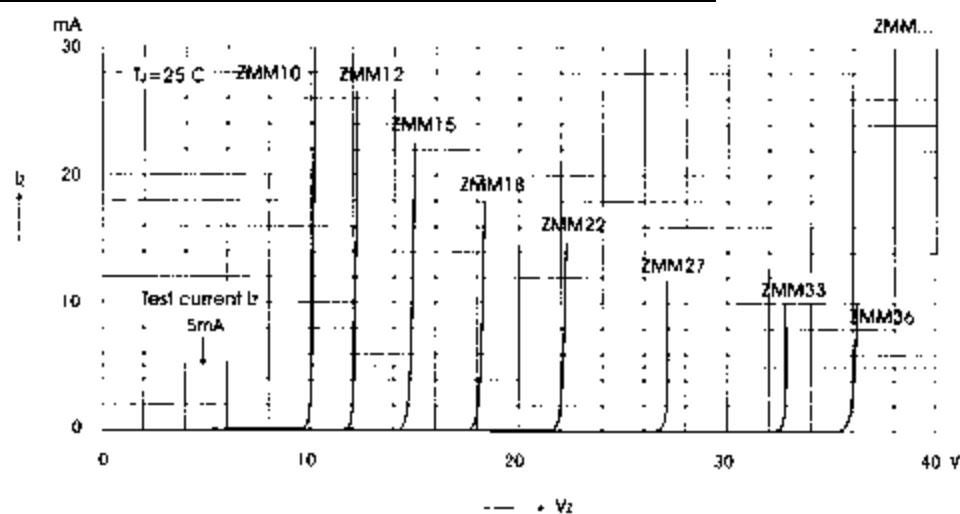
## 0.5W SILICON PLANAR ZENER DIODES

### ZMM1.ZMM200 SILICON PLANER ZENER DIODES

#### BREAKDOWN CHARACTERISTICS AT TJ=CONSTANT (PULSED)



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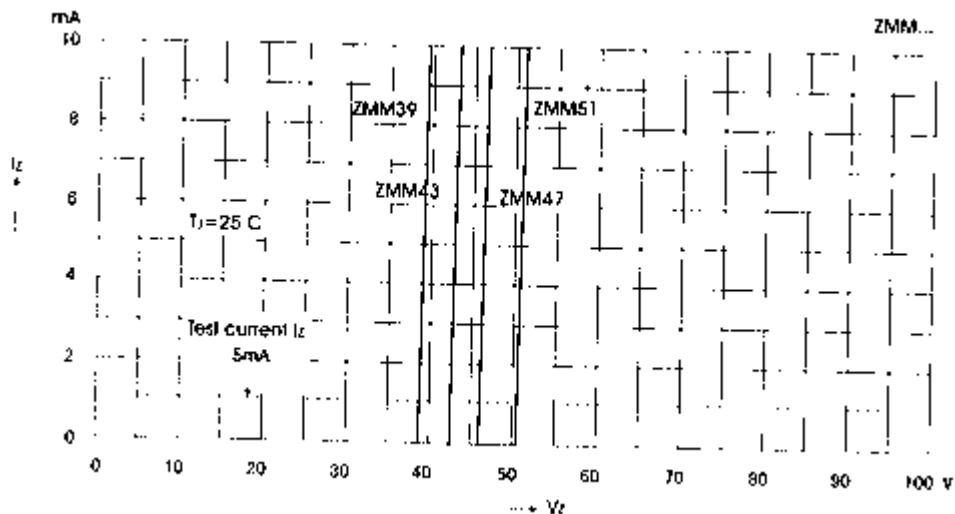


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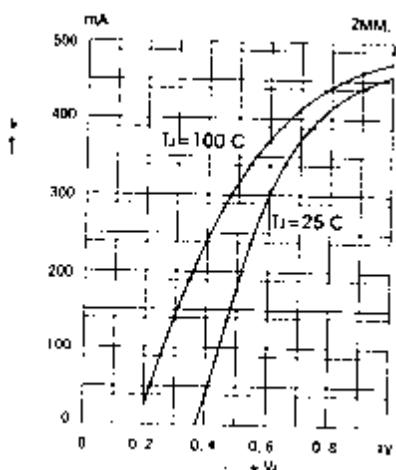
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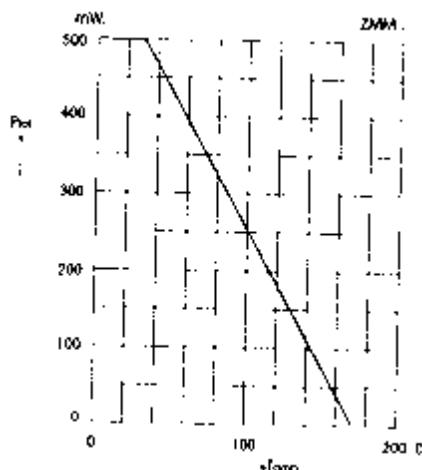
#### BREAKDOWN CHARACTERISTICS AT TJ=CONSTANT (PULSED)



#### Forward Characteristics

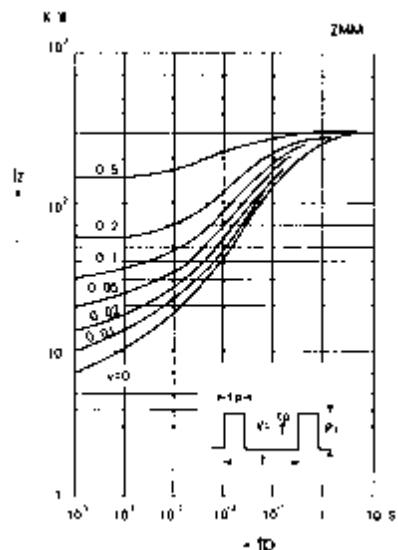


#### Admissible power dissipation versus ambient temperature

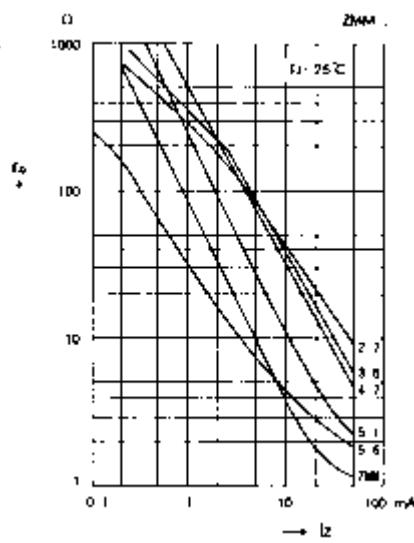


### ZMM1.ZMM200 SILICON PLANER ZENER DIODES

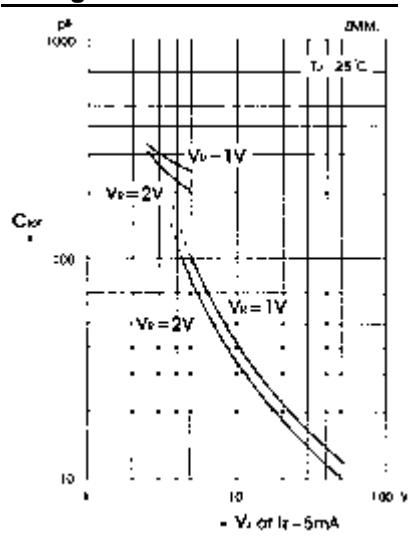
**Pulse thermal resistance versus  
pulse duration**



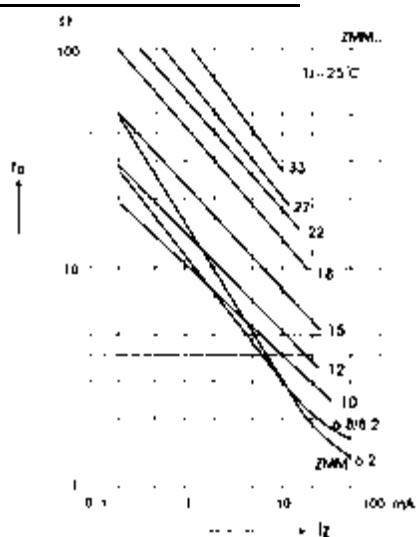
**Dynamic resistance versus  
Zener current**



**Capacitance versus Zener  
voltage**



**Dynamic resistance versus  
Zener current**

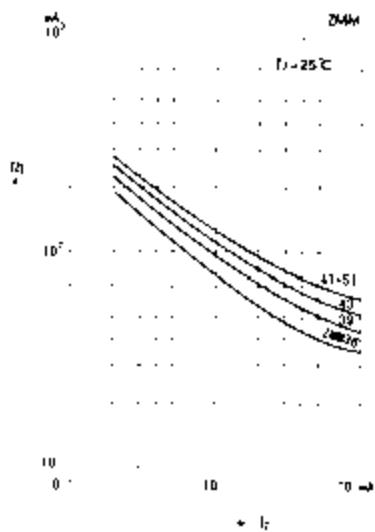


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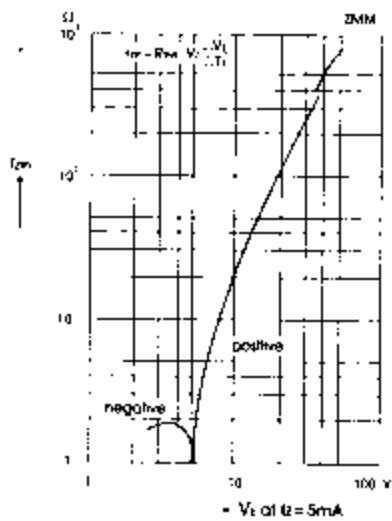
## **0.5W SILICON PLANAR ZENER DIODES**

## ZMM1.ZMM200 SILICON PLANER ZENER DIODES

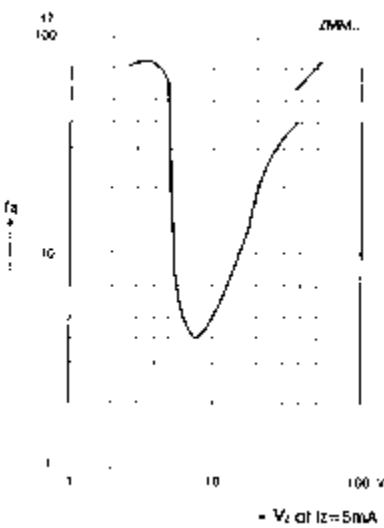
## Dynamic resistance versus Zener current



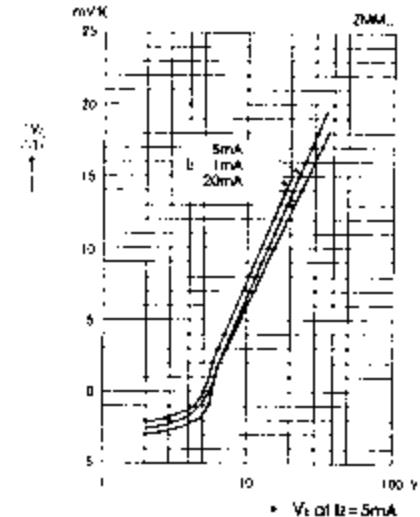
### **Thermal differential resistance versus Zener voltage**



## Dynamic resistance versus Zener voltage

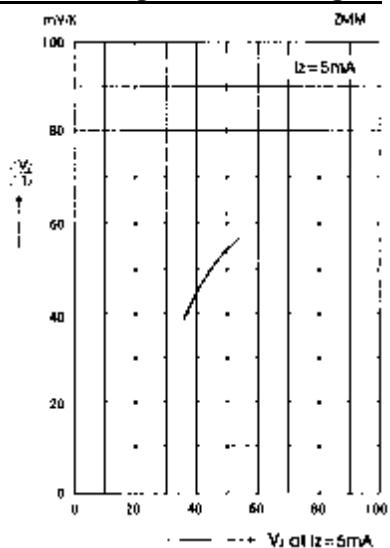


## Temperature dependence of Zener voltage versus voltage

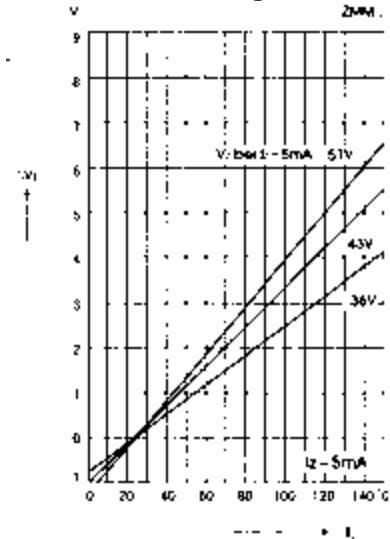


### ZMM1.ZMM200 SILICON PLANER ZENER DIODES

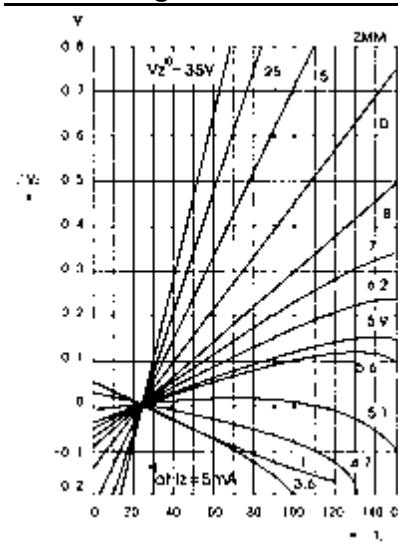
**Temperature dependence of  
Zener voltage versus voltage**



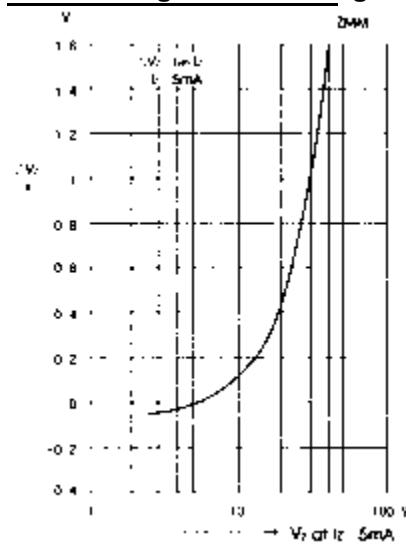
**Thermal differential resistance  
versus Zener voltage**



**Dynamic resistance versus  
Zener voltage**



**Temperature dependence of  
Zener voltage versus voltage**



### ZMM1.ZMM200 SILICON PLANER ZENER DIODES

Temperature dependence of  
Zener voltage versus voltage

